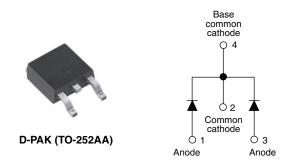
**Vishay Semiconductors** 

**RoHS** 

COMPLIANT HALOGEN

FREE

High Performance Schottky Rectifier, 2 x 6 A



www.vishay.com

PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I <sub>F(AV)</sub>	2 x 6 A						
V <sub>R</sub>	100 V						
V <sub>F</sub> at I <sub>F</sub>	0.65 V						
I <sub>RM</sub>	4 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
Diode variation	Common cathode						
E <sub>AS</sub>	6 mJ						

## **FEATURES**

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## DESCRIPTION

The VS-12CWQ10FN-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	12	A						
V <sub>RRM</sub>		100	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	330	A						
V <sub>F</sub>	6 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.65	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-12CWQ10FN-M3	UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	100	V						
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	v						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS						
Maximum average per leg		50 % duty avala at $T_{\rm c} = 135$ °C	6	А					
See fig. 5 per device	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 135 °C, rectangular waveform		12	~				
Maximum peak one cycle	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	330	A				
non-repetitive surge current per leg See fig. 7		10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	110					
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 12 mH		6	mJ				
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1	А				

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 1
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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		6 A	T <sub>.1</sub> = 25 °C	0.80	v			
Maximum forward voltage drop per leg	V (1)	12 A	1j=23 0	0.95				
See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	6 A	T <sub>1</sub> = 125 °C	0.65				
		12 A	1j = 125 C	0.78				
Maximum reverse	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		1	0			
leakage current per leg See fig. 2	IRM \''	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	4	mA			
Threshold voltage	V <sub>F(TO)</sub>	T T maximum			V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$	20.68	mΩ				
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ , (test signal ran	183	pF				
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	5.0	nH				

### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

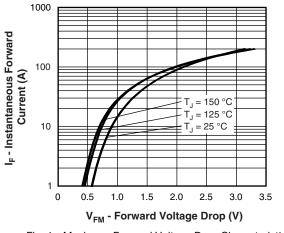
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-55 to +150	°C			
Maximum thermal resistance,	per leg	P	DC operation	3.0	°C/W			
junction to case	per device	R <sub>thJC</sub>	See fig. 4	1.5				
				0.3	g			
Approximate weight				0.01	oz.			
Marking device			Case style D-PAK (similar to TO-252AA)	12CWQ10FN				

## Note

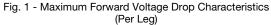
<sup>(1)</sup>  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

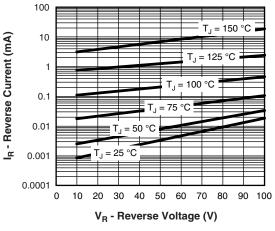


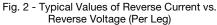
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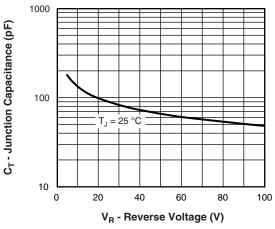


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

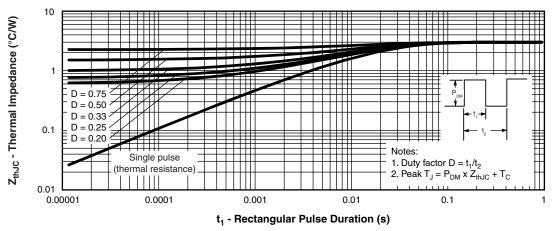
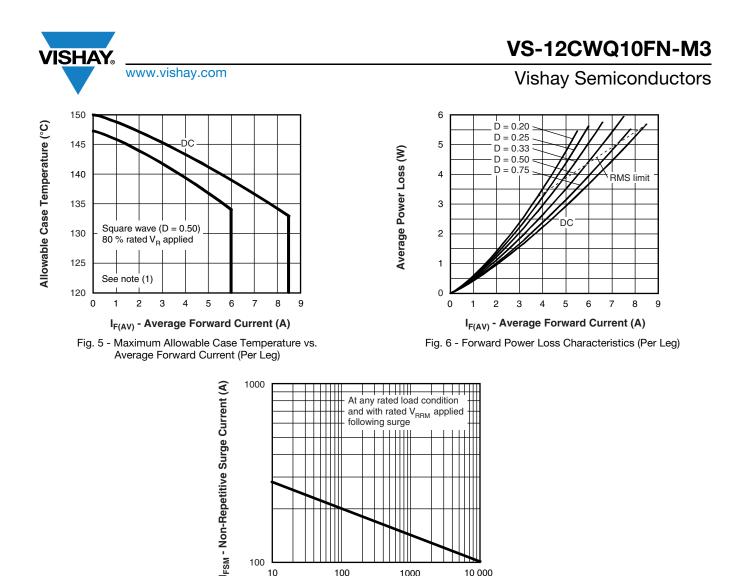


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



10 000

Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R at V_{R1} = 80 \%$  rated  $V_R$ 

100 10

100

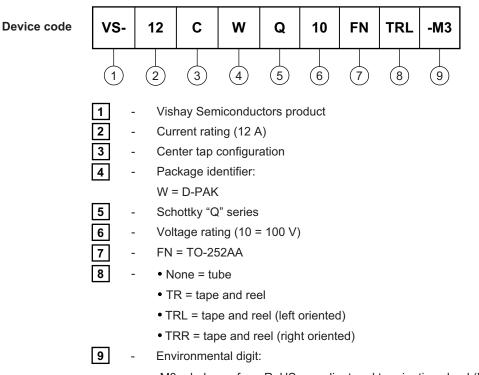
1000

t<sub>p</sub> - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

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-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-12CWQ10FN-M3	75	3000	Antistatic plastic tube							
VS-12CWQ10FNTR-M3	2000	2000	13" diameter reel							
VS-12CWQ10FNTRL-M3	3000	3000	13" diameter reel							
VS-12CWQ10FNTRR-M3	3000	3000	13" diameter reel							

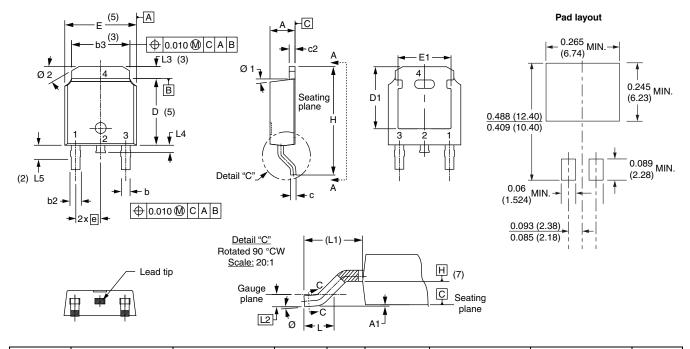
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95627						
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95177						





D-PAK (TO-252AA) "M"

## **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	HES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC		
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410		
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070		
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.		
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC		
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3	
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040		
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2	
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°		
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°		
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°		

### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA

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